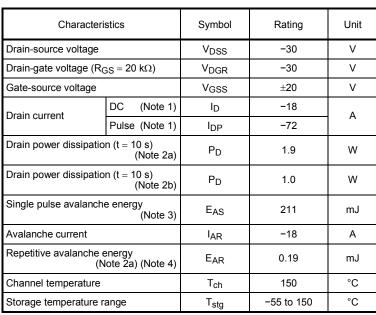
TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOSIV)

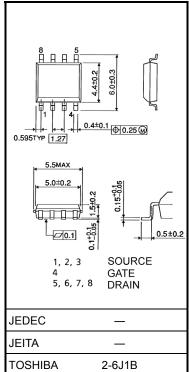
TPC8114

Lithium Ion Battery Applications Notebook PC Applications Portable Equipment Applications

- Small footprint due to small and thin package •
- Low drain-source ON resistance: R_{DS} (ON) = 3.1 m Ω (typ.)
- High forward transfer admittance: $|Y_{fs}| = 47 \text{ S} (typ.)$
- Low leakage current: $I_{DSS} = -10 \ \mu A \ (max) \ (V_{DS} = -30 \ V)$
- Enhancement mode: V_{th} = -0.8 to -2.0 V (V_{DS} = -10 V, I_D = -1 mA)

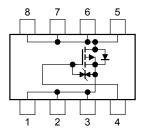


Absolute Maximum Ratings (Ta = 25°C)



Weight: 0.080 g (typ.)

Circuit Configuration



Note: (Note 1), (Note 2), (Note 3) and (Note 4): See the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

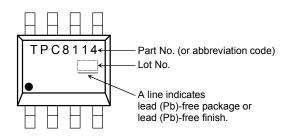
This transistor is an electrostatic-sensitive device. Please handle with caution.

Unit: mm

Thermal Characteristics

Characteristics	Symbol	Max	Unit	
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	R _{th (ch-a)}	65.8	°C/W	
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R _{th (ch-a)}	125	°C/W	

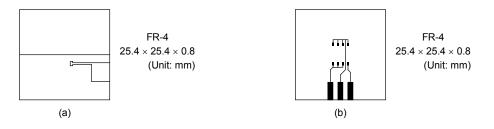
Marking (Note 5)



Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2:

(a) Device mounted on a glass-epoxy board (a) (b) Device mounted on a glass-epoxy board (b)



- Note 3: $V_{DD} = -24$ V, $T_{ch} = 25^{\circ}C$ (initial), L =500µH, $R_G = 25 \Omega$, $I_{AR} = -18$ A
- Note 4: Repetitive rating; pulse width limited by maximum channel temperature
- Note 5: on lower left of the marking indicates Pin 1.

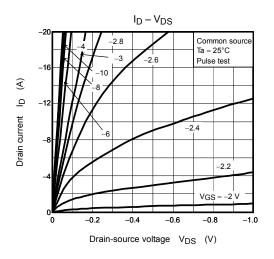


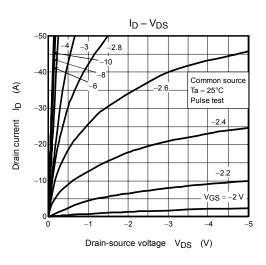
Electrical Characteristics (Ta = 25°C)

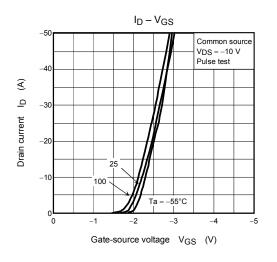
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit	
Gate leakage current		I _{GSS}	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$	_		±10	μA	
Drain cut-OFF current		I _{DSS}	$V_{DS}=-30~V,~V_{GS}=0~V$			-10	μA	
Drain-source breakdown voltage		V (BR) DSS	$I_D = -10$ mA, $V_{GS} = 0$ V	-30		_	v	
		V (BR) DSX	$I_D = -10$ mA, $V_{GS} = 20$ V	-15		_	v	
Gate threshold voltage		V _{th}	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -1 \text{ mA}$	-0.8		-2.0	V	
Drain-source ON resistance		Decker	$V_{GS} = -4 \ V, \ I_D = -9 \ A$	_	5.2	6.8	mΩ	
		R _{DS (ON)}	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -9 \text{ A}$	_	3.1	4.5		
Forward transfer admittance		Y _{fs}	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -9 \text{ A}$	23.5	47	_	S	
Input capacitance		C _{iss}		_	7480	_	pF	
Reverse transfer capacitance		C _{rss}	$V_{DS} = -10 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ f} = 1 \text{ MHz}$	_	1320	_		
Output capacitance		C _{oss}		_	1460	_		
Switching time	Rise time	tr	$V_{GS}_{-10} V \qquad I_{D} = -9 A$	_	25		- ns	
	Turn-ON time	t _{on}			36	_		
	Fall time	t _f	RL = 1		235	_		
	Turn-OFF time	t _{off}	$V_{DD}\simeq -15~V \label{eq:DD}$ Duty \leq 1%, $t_W=10~\mu s$		625	_		
Total gate charge (gate-source plus gate-drain)		Qg	$V_{DD} \simeq -24$ V, $V_{GS} = -10$ V, $I_D = -18$ A		180	_	nC	
Gate-source charge 1		Q _{gs1}		_	10	_		
Gate-drain ("miller") charge		Q _{gd}		_	60	_		

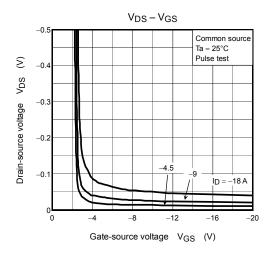
Source-Drain Ratings and Characteristics (Ta = 25°C)

Charac	teristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Drain reverse current	Pulse	(Note 1)	I _{DRP}	_	_	_	-72	А
Forward voltage (diode) V _{DSF}		V _{DSF}	$I_{DR} = -18 \text{ A}, V_{GS} = 0 \text{ V}$	_	_	1.2	V	

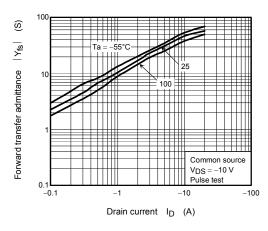




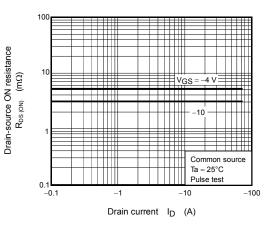


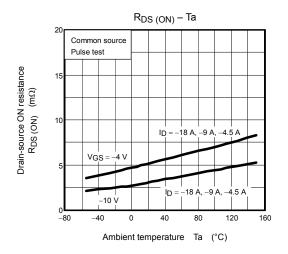


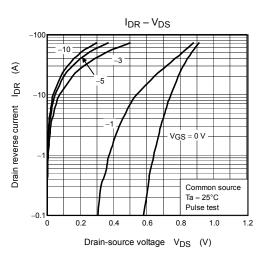


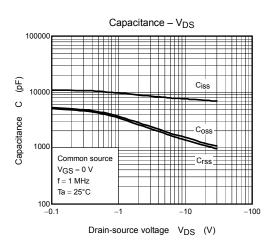


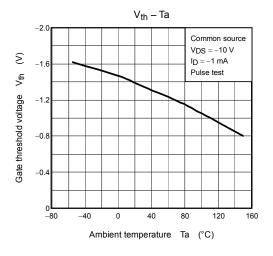
 $R_{DS(ON)} - I_D$

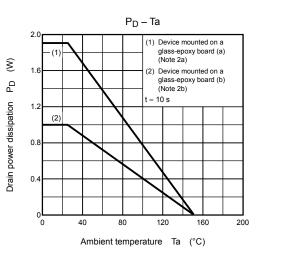


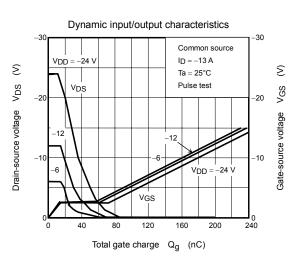


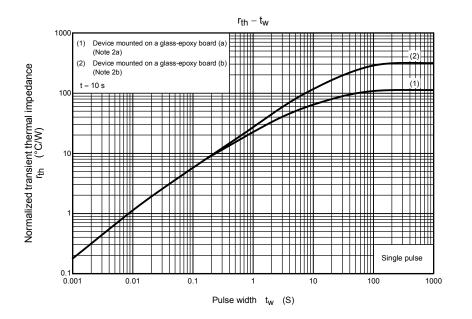




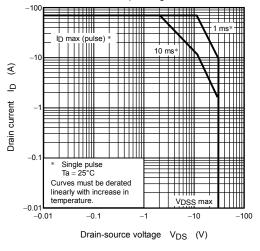








Safe operating area



RESTRICTIONS ON PRODUCT USE

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